NSN 5961-01-292-8224

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-292-8224 **Inclosure Material:** Metal **Overall Length:** Between 1.300 inches and 1.310 inches **End Application:** Md-3//md-4//ecu-105/e//ecu-110/e **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** Between 0.552 inches and 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage and 400.0 repetitive peak reverse voltage and 5.0 peak gate voltage **Current Rating Per Characteristic:** 6.40 amperes forward current, total rms universal and 90.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 75377-10692-014 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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